

**IMAGE DISPLAY DEVICE, AND DISPLAY PANEL AND DRIVING METHOD
THEREOF, AND PIXEL CIRCUIT**

CROSS REFERENCE TO RELATED APPLICATION

5 This application claims priority to and the benefit of Korean Patent Application No. 2003-0027604 filed on April 30, 2003 in the Korean Intellectual Property Office, the content of which is incorporated herein by reference.

BACKGROUND OF THE INVENTION

10 **(a) Field of the Invention**

The present invention relates to an image display device, and a display panel and driving method thereof. More specifically, the present invention relates to an organic electroluminescent (hereinafter, referred to as "EL") display device.

15 **(b) Description of the Related Art**

The organic EL display device, which is a display device for electrically exciting a fluorescent organic compound to emit a light, has organic light-emitting cells that are voltage- or current-driven to display an image. These organic light-emitting cells have a structure composed of an anode (indium tin oxide (ITO)) layer, an organic thin film, and a cathode (metal) layer. For a good balance between electrons and holes to enhance luminescent efficiency, the organic thin film has a multi-layer structure that includes an emitting layer (EML), an electron transport layer (ETL), and a hole transport layer (HTL). The multi-layer structure of the organic thin film can also include an electron injecting

layer (EIL), and a hole injecting layer (HIL).

There are two driving methods for these organic light-emitting cells: a passive matrix driving method, and an active matrix driving method using thin film transistors (TFTs). In the passive matrix driving method, anode and cathode stripes are arranged perpendicularly to each other to selectively drive the lines. On the other hand, in the active matrix driving method, a thin film transistor and a capacitor are coupled to ITO pixel electrodes so as to sustain a voltage by the capacity of the capacitor. According to the form of the signals applied to the capacitor to sustain the voltage, the active matrix driving method can be divided into a voltage programming method and a current programming method.

The voltage programming method is for displaying an image by applying a data voltage representing gradation to the pixel circuit, but may have a problem of non-uniformity due to a deviation of the threshold voltage of the driving transistor and the electron mobility. The current programming method is for displaying an image by applying a data current representing gradation to the pixel circuit, guaranteeing uniformity. But, this method is problematic in securing the time for charging the load of the data lines, since only a slight quantity of current is used in controlling the organic EL element.

A pixel circuit for compensating for the threshold voltage of the driving transistor in the voltage programming method is disclosed in U.S. Patent No. 6,362,798 issued to Kimura et al.

The pixel circuit disclosed in U.S. Patent No. 6,362,798 includes, as shown in Fig. 1, four transistors M1 to M4, and an organic EL element (OLED).

The driving transistor M1 transfers a current corresponding to a voltage between its gate and source to OLED, and has a capacitor Cst between the gate and source. The transistor M2 is configured to operate as a diode (i.e., its gate and drain are connected together) and has the gate connected to the gate of the transistor M1. A gate of the switching transistor M3 is connected to a current scan line S_n , and a gate of the transistor M4 is connected to a previous scan line S_{n-1} .

When the threshold voltage of the transistor M1 is equal to that of the transistor M2, it can be compensated due to the transistor M2. But, when the gate voltage of the driving transistor M1 is higher than the data voltage applied through the transistor M3, the transistor M2 is diode-connected (i.e., configured to operate as a diode) in a reverse direction, as a result of which the data voltage cannot be transferred to the gate of the driving transistor M1. To prevent this phenomenon in the prior art, the precharge voltage V_P is applied to the gate of the driving transistor M1 and sustained to be less than the lowest data voltage, while a selection signal is applied to the previous scan line S_{n-1} . In this manner, the gate voltage of the driving transistor M1 reaches the precharge voltage V_P when the data voltage is applied, thereby coupling the transistor M2 in the forward direction.

A current flows through the driving transistor M1 due to a voltage corresponding to the difference between the precharge voltage V_P and the power voltage V_{DD} , when the precharge voltage V_P is transferred to the gate of the driving transistor M1. This current causes the OLED to emit a light, in which case normal black level cannot be displayed to represent black level gradation.

Moreover, the current flows to the OLED while the data voltage is transferred to the gate of the driving transistor M1 and charged in the capacitor C_{st}, thereby increasing power consumption.

SUMMARY OF THE INVENTION

5 In one exemplary embodiment of the present invention, there is provided an image display device that compensates for the threshold voltage of the driving transistor and prevents an unnecessary current flowing to the display element. In said one exemplary embodiment, a transistor may be added between the driving transistor and the display element.

10 In an exemplary embodiment of the present invention, there is provided a display panel for image display that includes a plurality of data lines for transferring a data voltage representing an image signal, a plurality of scan lines, each scan line for transferring a selection signal, and a plurality of pixel circuits, each pixel circuit being coupled to a corresponding said data line and two adjacent said scan lines. The pixel circuit includes a display element, first and second transistors, and first, second and third switching elements. The first transistor generates a current corresponding to a voltage between its main electrode and control electrode. A capacitor is coupled between the main electrode and the control electrode. The second transistor is configured to operate as a diode, and has a control electrode coupled to the control electrode of the first transistor. The first switching element is coupled to a main electrode of the second transistor, and transfers the data voltage from the data lines to the second transistor in response to the selection signal from one of the two

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adjacent scan lines. The second switching element transfers a precharge voltage to the control electrode of the first transistor in response to a first control signal before the data voltage is supplied. The third switching element is turned off in response to a second control signal for electrically isolating the first transistor from the display element.

In another exemplary embodiment, the data voltage is applied to the data lines after transferring the precharge voltage in response to the first control signal and before applying the selection signal to the current scan line.

In another exemplary embodiment, the second control signal includes the first control signal. The selection signal from the previous scan line is used as both the first and second control signals. The second switching element is a transistor of a first conductive type, and the third switching element is a transistor of a second conductive type, which is an opposite of the first conductive type.

In another exemplary amendment of the present invention, the second control signal is a selection signal from the current scan line. The second switching element is a transistor of a first conductive type, and the third switching element is a transistor of a second conductive type, which is an opposite of the first conductive type. The first control signal is a selection signal from a previous scan line.

In yet another exemplary embodiment of the present invention, there is provided an image display device that includes the above-described display panel.

In still another exemplary embodiment of the present invention, there is

provided a method for driving an image display device coupled to two adjacent scan lines. The image display device includes a first transistor having a main electrode and a control electrode with a capacitor coupled therebetween, the first transistor capable of generating a current corresponding to a voltage charged in the capacitor, a second transistor having a control electrode coupled to the control electrode of the first transistor and being configured to operate as a diode, and a display element capable of displaying a portion of an image corresponding to a quantity of the current generated by the first transistor. The method includes: transferring a precharge voltage to the control electrode of the first transistor in response to a first control signal during a first time period; transferring a data voltage to the control electrode of the first transistor through the second transistor in response to a selection signal from one of the two adjacent scan lines during a second time period; and interrupting the transfer of the data voltage. The first transistor is electrically isolated from the display element during at least one of the first time period and the second time period.

In a further exemplary embodiment, the first control signal is a selection signal from a previous scan line. The first transistor is electrically isolated from the display element in response to the first control signal during the first time period.

In a still further exemplary embodiment, the first transistor is electrically isolated from the display element in response to the second control signal during the second time period. The second control signal is a selection signal from the current scan line.

In yet further exemplary embodiment, a time period of preventing the

precharge voltage and the data voltage from being transferred to the control electrode of the first transistor is included between the first and second time periods.

In still another exemplary embodiment of the present invention, there is provided a pixel circuit, which responds to a precharge voltage from a first signal line and a data voltage representing an image signal from a second signal line. The pixel circuit includes first and second transistors, a display element, and switching means. The first transistor has a main electrode and a control electrode with a capacitor coupled therebetween, and is capable of generating a current in response to a voltage charged in the capacitor. The second transistor has a control electrode coupled to the control electrode of the first transistor and is configured to operate as a diode. The display element is capable of displaying a portion of an image, said image portion corresponding to the current generated by the first transistor. The switching means is coupled between the first transistor and the display element. The precharge voltage is applied to the control electrode of the first transistor in response to a control signal for a first time period, and the data voltage is applied to the control electrode of the first transistor in response to a select signal for a second time period. The first transistor is electrically isolated from the display element by the switching means during at least one of the first time period and the second time period.

In yet another exemplary embodiment of the present invention is provided a display device that includes a display element, a first transistor, a first switching element and a capacitor. The display element is for displaying a

portion of an image in response to a current being applied. The first transistor has a main electrode and a control electrode, and is coupled between a voltage source and the display element. The capacitor is coupled between the main electrode and the control electrode, wherein the first transistor is capable of generating the current in response to a charge in the capacitor. The first switching element is coupled between the first transistor and the display element to interrupt the current to the display element while charging the capacitor using at least one of a precharge voltage and a data voltage representative of the image portion.

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BRIEF DESCRIPTION OF THE DRAWINGS

The accompanying drawings, which together with the specification, illustrate exemplary embodiments of the present invention, and, together with the description, serve to explain the principles of the present invention:

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Fig. 1 is an equivalent circuit diagram of a pixel circuit according to prior art;

Fig. 2 is a schematic diagram of an organic EL display device according to an embodiment of the present invention;

Figs. 3, 5, 7, 8 and 10 are equivalent circuit diagrams of pixel circuits according to exemplary embodiments of the present invention;

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Figs. 4, 6 and 11 are driving waveform diagrams for driving the pixel circuits shown in Figs. 3, 5 and 10, respectively; and

Fig. 9 is a diagram showing graphs that depict a current flowing to the organic EL element in the pixel circuit.

DETAILED DESCRIPTION

In the following detailed description, exemplary embodiments of the present invention are shown and described, by way of illustration. As those skilled in the art would recognize, the described embodiments may be modified in various different ways, all without departing from the spirit or scope of the present invention. Accordingly, the drawings and description are to be regarded as illustrative in nature, and not restrictive.

The parts not related to the description are omitted in the Figures for more definite description of the present invention. When a component is described as being coupled to another component it refers to cases where the two components are directly coupled to each other, and additionally to cases where the two components are coupled to each other with a third element between them.

Now, reference will be made to Fig. 2 in the description of an organic EL display device according to an exemplary embodiment of the present invention. Fig. 2 is a schematic diagram of the organic EL display device according to the exemplary embodiment of the present invention.

The organic EL display device according to the described embodiment of the present invention includes, as shown in Fig. 2, an organic EL display panel 10, a scan driver 20, and a data driver 30.

The organic EL display panel 10 includes a plurality of data lines D_1 to D_M arranged in columns, a plurality of scan lines S_1 to S_N arranged in rows, and a plurality of pixel circuits 11. The data lines D_1 to D_M transfer a data voltage representing an image signal to the pixel circuits 11. The scan lines S_1 to S_N

transfer a selection signals for selecting the pixel circuits 11. Each of the pixel circuits 11 is formed in a pixel area defined by two adjacent data lines and two adjacent scan lines.

5 The scan driver 20 sequentially applies the selection signal to the scan lines S_1 to S_N , and the data driver 30 applies the data voltage representing an image signal to the data lines D_1 to D_M .

The scan driver 20 and/or the data driver 30 can be coupled to the display panel 10, or mounted in the form of a chip on a tape carrier package (TCP) that is coupled to the display panel 10 by soldering. The scan driver 20 and/or the data driver 30 can also be mounted in the form of a chip on a flexible printed circuit (FPC) or a film coupled to the display panel by soldering. This method is called “CoF (Chip on Flexible board, or Chip on Film)”. Further, the scan driver 20 and/or the data driver 30 can be mounted directly on the glass substrate of the display panel, or replaced for the driving circuit that includes the same layers as scan and data lines and thin film transistors on the glass substrate. This method is called “CoG (Chip on Glass)”. In other embodiments, the scan driver 20 and/or the data driver 30 may be mounted on any other suitable location using any suitable mounting method.

20 Next, the pixel circuit 11 of the organic EL display panel according to an exemplary embodiment of the present invention will be described in detail with reference to Figs. 3 and 4. Fig. 3 is an equivalent circuit diagram of the pixel circuit according to the exemplary embodiment of the present invention, and Fig. 4 is a driving waveform diagram for driving the pixel circuit shown in Fig. 3. For example, the pixel circuit is coupled to the m -th data line D_m and the n -th scan

line S_n in Fig. 3. The pixel circuit may be coupled to any other data line/scan line combination illustrated in Fig. 2. The term “current scan line” as used herein refers to a scan line for transferring a current selection signal, and the term “previous scan line” as used herein refers to a scan line for transferring a selection signal prior to the current selection signal.

The pixel circuit 11 according to the exemplary embodiment of the present invention includes, as shown in Fig. 3, an organic EL element (OLED), transistors M1 to M5, and a capacitor C_{st} . The transistors M1 to M4 are PMOS type transistors, and the transistor M5 is an NMOS type transistor. These transistors M1 to M5 should be thin film transistors, each of which has gate, drain and source electrodes formed on the glass substrate of the display panel 10 as a control electrode and two main electrodes, respectively.

The driving transistor M1 has a source electrode coupled to a power voltage V_{DD} . A capacitor C_{st} is coupled between the source electrode and a gate electrode. The capacitor C_{st} sustains gate-source voltage V_{GS} of the transistor M1 for a period of time, which may be predefined. The compensating transistor M2 is configured to operate as a diode (i.e., its gate and drain are coupled together). The gate of the compensating transistor M2 is also coupled to the gate of the transistor M1. The switching transistor M3 transfers, to the transistor M2, a data voltage from the data line D_m in response to a selection signal from the current scan line S_n . The drain of the transistor M2 is coupled to the transistor M4. The transistor M4 transfers a precharge voltage V_P to the transistor M2 in response to the selection signal from the previous scan line S_{n-1} .

The transistor M5 is coupled between the drain of the transistor M1 and

the anode of the OLED, and electrically isolates the transistor M1 from the OLED in response to the selection signal from the previous scan line S_{n-1} . The OLED has a cathode coupled to a reference voltage V_{ss} , and emits a light corresponding to the current applied. The reference voltage V_{ss} is lower than the power voltage V_{DD} and may be a ground voltage.

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Now, the operation of the pixel circuit according to the exemplary embodiment of the present invention will be described in detail with reference to Fig. 4.

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Referring to Fig. 4, during a precharge time period T1, the selection signal from the previous scan line S_{n-1} becomes “low” to turn the transistor M4 on and the transistor M5 off. With the transistor M4 on, the precharge voltage V_P is transferred to the gate of the transistor M1. The precharge voltage V_P is slightly lower than any data voltage applied to the gate of the transistor M1 through the transistor M2 (taking into account the voltage drops in the transistors M2 and M4, respectively), i.e., the lowest data voltage applied through the data line D_m , for the sake of acquiring a maximum gradation level. In this manner, the data voltage is always higher than the gate voltage of the transistor M1 when it is applied through the data line D_m . Therefore, the transistor M1 is coupled in the forward direction so that the data voltage is charged in the capacitor C_{st} .

During the precharge time period T1, the gate-source voltage V_{GS} of the transistor M1 is increased due to the precharge voltage V_P , so that a high current would flow through the transistor M1 if a current path is available. If supplied to the OLED, this current would cause the OLED to emit a light,

thereby preventing an accurate representation of a black level gradation. According to the exemplary embodiment of the present invention, the turned-off transistor M5 electrically isolates the transistor M1 from the organic OLED to prevent a current flow, which otherwise would have been caused by the 5 precharge voltage V_P . This enables an accurate representation of black level gradation and prevents an unnecessary current flow, thereby also reducing power consumption.

During a blanking time period T2, the selection signal from the previous scan line S_{n-1} becomes “high” while the selection signal from the current scan 10 line S_n is sustained at a high level. In this time period T2, the voltage on the data line D_m is changed to a data voltage corresponding to the pixel circuit coupled to the current scan line S_n . In other words, voltage on the data line D_m should be saturated to a desired data voltage during the blanking time period T2. Without the blanking time period T2, the previous data voltage applied to 15 the data line D_m may be transferred to the transistor M1 via the transistor M3 when the selection signal from the current scan line S_n becomes “low” before the current data voltage is applied.

During a data charge period T3, the selection signal from the current scan line S_n becomes “low” to turn the transistor M3 on. Then the data voltage 20 from the data line D_m is transferred to the transistor M2 through the transistor M3. The transistor M2 is configured to operate as a diode, so the voltage corresponding to the data voltage minus threshold voltage V_{TH2} of the transistor M2 is transferred to the gate of the transistor M1. This voltage is charged in the capacitor C_{st} and sustained for a period of time, which may be predefined.

Further, the selection signal from the previous scan line S_{n-1} becomes “high” to turn the transistor M5 on. In practice, as indicated on FIG. 4, the selection signal line S_{n-1} from the previous scan line becomes “high” during the blanking time period T2, thereby turning on the transistor M5.

5 During a light-emitting time period T4, a current I_{OLED} corresponding to the gate-source voltage V_{GS} of the transistor M1 is supplied to the OLED, so the OLED emits a light. The current I_{OLED} can be defined as follows.

[Equation 1]

$$I_{OLED} = \frac{\beta}{2} (|V_{GS}| - |V_{TH1}|)^2 = \frac{\beta}{2} (V_{DD} - (V_{DATA} - |V_{TH2}|) - |V_{TH1}|)^2$$

10 where V_{TH1} is the threshold voltage of the transistor M1; V_{DATA} is the data voltage from the data line D_m ; and β is a constant.

When the threshold voltage V_{TH1} of the transistor M1 is equal to the threshold voltage V_{TH2} of the transistor M2, the equation 1 can be rewritten as:

[Equation 2]

$$I_{OLED} = \frac{\beta}{2} (V_{DD} - V_{DATA})^2$$

15 Accordingly, a current corresponding to the data voltage applied through the data line D_m flows to the OLED irrespective of the threshold voltage V_{TH1} of the transistor M1.

In this manner, the exemplary embodiment of the present invention compensates for a deviation of the threshold voltage of the driving transistor M1 and prevents the current from flowing to the OLED caused by the precharge voltage V_P .

The pixel circuit according to the exemplary embodiment of the present invention uses the previous scan line S_{n-1} so as to control the transistors M4 and M5. In other embodiments, a separate control line (not shown) may be used to transfer a control signal for turning the transistor M4 on and/or the transistor M5 off during the precharge time period T1.

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In the exemplary embodiment of the present invention, the type of the transistor M5 is an opposite of that of the transistor M4 so as to turn the transistor M5 off during the precharge time period T1. The transistor M5 may have the same type as the transistor M4 in another embodiment of the present invention, which will be described, for example, in detail with reference to Figs. 5 and 6 as follows.

Fig. 5 is an equivalent circuit diagram of the pixel circuit according to another exemplary embodiment of the present invention, and Fig. 6 is a driving waveform diagram for driving the pixel circuit shown in Fig. 5.

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The pixel circuit according to this exemplary embodiment of the present invention has the same structure as the exemplary embodiment of Fig. 3 except for the type of the transistor M6 (which is different from the type of the transistor M5 of Fig. 3) and an addition of a control line C_n . More specifically, the transistor M6 is a PMOS type transistor, which is the same type as the transistors M1 to M4, and turns off in response to a “high” control signal from the control line C_n . The control signal applied to the control line C_n is an inversed form of the selection signal applied to the previous scan line S_{n-1} , as shown in Fig. 6. Hence, the transistor M6 is turned off during the precharge time period T1 to interrupt the current flowing to the OLED, as in the exemplary

embodiment of Fig. 3.

In this manner, this exemplary embodiment implements the pixel circuit with the transistors of the same type, thereby simplifying the fabrication process relative to the exemplary embodiment of Fig. 3.

5 The above described exemplary embodiments additionally use the transistors M5 and M6, respectively, so as to interrupt the current flowing to the OLED during the precharge time period T1. In other exemplary embodiments, a transistor may be added in addition to (or instead of) the transistor M5 or M6, and the driving waveform may be selected so as to interrupt the current flowing 10 to the OLED during the data charge time period T3. One such exemplary embodiment will be described in detail with reference to Fig. 7 as follows.

Fig. 7 is an equivalent circuit diagram of a pixel circuit according to yet another exemplary embodiment of the present invention.

Referring to Fig. 7, the pixel circuit according to this exemplary embodiment has a transistor M5 coupled between the transistor M1 and the OLED. . The transistor M5 is an NMOS type transistor similar to the transistor M5 of Fig. 3. However, the transistor M5 has a gate coupled to the current scan line S_n . The pixel circuit in this exemplary embodiment is driven by the driving waveform of Fig. 4.

20 In this manner, the transistor M5 is turned off in response to the selection signal from the current scan line S_n to electrically isolate the transistor M1 from the OLED while the data voltage from the data line D_m is charged in the capacitor C_{st} during the data charge time period T3. Thus, the current flowing to the OLED is interrupted while the data voltage is charged in the

capacitor C_{st} .

As the selection signal from the current scan line S_n becomes “high”, the transistor M5 is turned on to couple the transistor M1 to the OLED. Hence, a current I_{OLED} corresponding to the voltage charged in the capacitor C_{st} flows to the OLED, which then emits light in the light-emitting time period T4. Therefore, in this embodiment, the current flowing to the OLED is interrupted while the data voltage is charged, thereby reducing power consumption.

In yet another exemplary embodiment, the transistor M5 may be of the same transistor type as the switching transistor M3. In that exemplary embodiment, the transistor M5 may be driven by a signal of an inversed form of the selection signal applied to the scan line S_n to realize an equivalent pixel circuit as the pixel circuit of Fig. 7.

In the exemplary embodiment of Fig. 7, the current does not flow (i.e., is interrupted) to the OLED during the data charge time period T3. The current flowing to the OLED may also be interrupted during the precharge time period T1 in other exemplary embodiments, one of which will be described in detail with reference to Figs. 8 and 9 as follows.

Fig. 8 is an equivalent circuit diagram of the pixel circuit according to still another exemplary embodiment of the present invention, and Fig. 9 shows a current flowing to the OLED in the pixel circuits shown in Figs. 1, 3 and 8, respectively.

Referring to Fig. 8, the pixel circuit according to this exemplary embodiment has a transistor M7 added to the pixel circuit in the exemplary embodiment of Fig. 3. For example, the transistors M7 and M5 are coupled in

series between the transistor M1 and the anode of the OLED, and formed with NMOS transistors. The gate of the transistor M5 is coupled to the previous scan line S_{n-1} , and that of the transistor M7 is coupled to the current scan line S_n . Here, the transistors M5 and M7 can be switched in position. The pixel circuit of Fig. 8 is driven using the driving waveform of Fig. 4.

In this manner, the transistor M5 is turned off in response to the selection signal from the previous scan line S_{n-1} during the precharge time period T1, so that no current flows to the OLED in response to the precharge voltage V_p . Further, the transistor M7 is turned off in response to the selection signal from the current scan line S_n during the data charge time period T3, so that no current flows to the OLED while the data voltage is charged. In the light-emitting time period T4, both the transistors M5 and M7 are turned on, and a current corresponding to the voltage charged in the capacitor C_{st} flows to the OLED.

In other embodiments, the transistor M5 may have the same transistor type as the transistor M4 and applied with a signal having an inverted form of the selection signal applied to the previous scan line S_{n-1} to the gate of the transistor M5. Similarly, the transistor M7 may be formed to have the same transistor type as the transistor M3, and applied with a signal having an inverted form of the selection signal applied to the current scan line S_n . The operation of such pixel circuits would be equivalent to that of the pixel circuit of FIG. 8.

Referring to Fig. 9, the pixel circuit of Fig. 1, as shown on graph 100, allows a current to flow to the OLED during both the precharge time period T1

and the data charge time period T3. On the other hand, the pixel circuit of Fig. 3, as shown on graph 110, allows a current to flow to the OLED not in the precharge time period T1 but in the data charge time period T3. Unlike the pixel circuits of Figs 1 and 3, the pixel circuit of Fig. 8, as shown on graph 120 does not allow a current to flow to OLED during both the precharge time period T1 and the data charge time period T3.

Although the transistors M1 to M4 are formed with PMOS type transistors in the above described exemplary embodiments, they may also be formed with NMOS type transistors in other embodiments. One such exemplary embodiment will be described in detail with reference to Figs. 10 and 11. In still other embodiments, the transistors M1 to M4 may be any other suitable transistors.

Fig. 10 is an equivalent circuit diagram of the pixel circuit according to a still further exemplary embodiment of the present invention, and Fig. 11 is a driving waveform diagram for the pixel circuit shown in Fig. 10.

The pixel circuit according to this embodiment, as shown in Fig. 10, has transistors M11 to M14 formed with NMOS type transistors, and transistors M15 and M16 formed with PMOS type transistors. The pixel circuit of Fig. 10 also has a structure that is symmetrical to the pixel circuit of Fig. 8. More specifically, the transistor M11 has a source electrode coupled to the reference voltage V_{SS} , and the OLED has an anode coupled to the power voltage V_{DD} . The transistors M15 and M16 are coupled in series between the cathode of the OLED and the drain of the transistor M11.

Referring to Fig. 11, the driving waveform for the pixel circuit of Fig. 10

has an inverted form of the driving waveform (in Fig. 4) of the pixel circuit of Fig. 8. The pixel circuit of Fig. 10 performs an equivalent operation as the pixel circuit of Fig. 8, and its operation will not be described in detail.

The transistors M11 to M14 formed with NMOS type transistors can be applied to all the embodiments of the present invention. Likewise, if the same functions of the above-stated transistors are enabled, the pixel circuit can be implemented with a combination of PMOS and NMOS transistors or other switching elements.

As described above, the exemplary embodiments according to the present invention may compensate for a deviation of the threshold voltage of the transistors when the driving transistor has the same threshold voltage as the compensating transistor. In the pixel circuits of the exemplary embodiment, a current may not be provided to the OLED while the precharge voltage is being charged in a capacitor, thereby allowing an accurate representation of black level gradation, which may enhance a contrast ratio. Further, a current may not be provided to the OLED while the data voltage is being charged, thereby reducing power consumption.

Although exemplary embodiments of the present invention have been described by way of an organic EL display device, the present invention is not specifically limited to the organic EL display device and may be applied to other light-emitting display devices that emit a light in response to the current applied.

While this invention has been described in connection with certain exemplary embodiments, it is to be understood that the invention is not limited to the disclosed exemplary embodiments, but, on the contrary, is intended to

cover various modifications and equivalent arrangements included within the spirit and scope of the appended claims.